# 74AVC1T1004 1-to-4 fan-out buffer Rev. 1 — 23 April 2018

**Product data sheet** 

#### **General description** 1

The 74AVC1T1004 is a translating 1-to-4 fan-out buffer suitable for use in clock distribution. It has dual supplies ( $V_{CC(A)}$  and  $V_{CC(B)}$ ) for voltage translation. It also has a data input (A), four data outputs (Yn) and an output enable input ( $\overline{OE}$ ).  $V_{CC(A)}$  and  $V_{CC(B)}$ can be independently supplied at any voltage between 0.8 V and 3.6 V. It makes the device suitable for low voltage translation between any of the following voltages: 0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V and 3.3 V. The levels of A and  $\overline{OE}$  are referenced to  $V_{CC(A)}$ , outputs Yn are referenced to  $V_{CC(B)}$ . This supply configuration ensures that the fanned out signals can be used in level shifting. A HIGH on OE causes all outputs to be pulled LOW via pull-down resistors, a LOW on  $\overline{OE}$  disconnects the pull-down resistors and enables all outputs.

Schmitt trigger action at all inputs makes the circuit tolerant for slower input rise and fall time.

The I<sub>OFF</sub> circuitry disables the output, preventing any damaging backflow current through the device when it is powered down.

#### **Features and benefits**

- Wide supply voltage range:
  - V<sub>CC(A)</sub>: 0.8 V to 3.6 V
  - V<sub>CC(B)</sub>: 0.8 V to 3.6 V
- Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM ANSI/ESDA/JEDEC JS-001 Class 2 exceeds 2 kV
  - CDM JESD22-C101 exceeds 1000 V
- Maximum data rates:
  - 380 Mbit/s (≥ 1.8 V to 3.3 V translation)
  - 200 Mbit/s (≥ 1.1 V to 3.3 V translation)
  - 200 Mbit/s (≥ 1.1 V to 2.5 V translation)
  - 200 Mbit/s (≥ 1.1 V to 1.8 V translation)
  - 150 Mbit/s (≥ 1.1 V to 1.5 V translation)
  - 100 Mbit/s (≥ 1.1 V to 1.2 V translation)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



### 3 Ordering information

#### **Table 1. Ordering information**

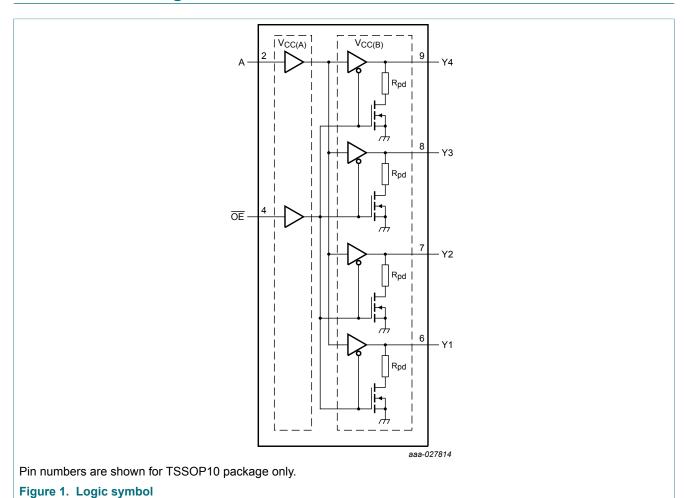
Type number	Package									
	Temperature range	Name	Description	Version						
74AVC1T1004DP	-40 °C to +125 °C	TSSOP10	plastic thin shrink small outline package; 10 leads; body width 3 mm	SOT552-1						
74AVC1T1004GU33	-40 °C to +125 °C	X2QFN10	plastic extremely thin small outline package; no leads; 10 terminals; body 1.6 x 1.3 x 0.33 mm	SOT1430-1						

### 4 Marking

#### Table 2. Marking codes

Type number	Marking code
74AVC1T1004DP	Вс
74AVC1T1004GU33	Вс

### 5 Functional diagram



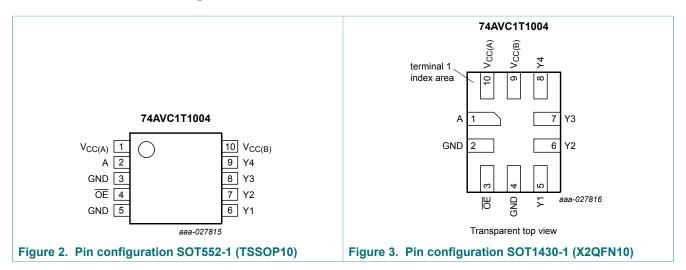
74AVC1T1004

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### 6 Pinning information

### 6.1 Pinning



### 6.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	SOT552-1	SOT1430-1	
V <sub>CC(A)</sub>	1	10	supply voltage A
A	2	1	data input (referenced to V <sub>CC(A)</sub> )
GND <sup>[1]</sup>	3, 5	2, 4	ground (0 V)
ŌĒ	4	3	output enable input (active LOW) (referenced to $V_{\text{CC(A)}}$ )
Y1, Y2, Y3, Y4	6, 7, 8, 9	5, 6, 7, 8	data outputs (referenced to $V_{\text{CC(B)}}$ )
V <sub>CC(B)</sub>	10	9	supply voltage B

<sup>[1]</sup> All GND pins must be connected to ground (0 V).

### **Functional description**

Table 4. Function table [1]

Inputs	Output			
ŌE	A	Yn		
L	L	L		
L	Н	Н		
Н	X	L		

<sup>[1]</sup> H = HIGH voltage level;

### **Limiting values**

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		-0.5	+4.6	V
V <sub>CC(B)</sub>	supply voltage B		-0.5	+4.6	V
VI	input voltage	[1]	-0.5	+4.6	V
Vo	output voltage	OE = LOW [1] [2]	-0.5	V <sub>CC(B)</sub> + 0.5	V
		OE = HIGH	-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Io	output current	$V_O = 0 V \text{ to } V_{CC(B)}$	-	±50	mA
I <sub>CC</sub>	supply current	I <sub>CC(A)</sub> or I <sub>CC(B)</sub>	-	100	mA
I <sub>GND</sub>	ground current		-100	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C			
		SOT552-1 package [3]	-	250	mW
		SOT1430-1 package [4]	-	250	mW

<sup>[1]</sup> The minimum input voltage ratings and output voltage ratings may be exceeded if the input and output current ratings are observed.

L = LOW voltage level;

X = don't care.

 <sup>[2]</sup> V<sub>CC(B)</sub> + 0.5 V should not exceed 4.6 V.
 [3] For SOT552-1 package: above 120 °C, the value of P<sub>tot</sub> derates linearly with 8.3 mW/K.
 [4] For SOT1430-1 package: above 100 °C, the value of P<sub>tot</sub> derates linearly with 5.2 mW/K.

### 9 Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC(A)</sub>	supply voltage A		0.8	3.6	V
V <sub>CC(B)</sub>	supply voltage B		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	OE = LOW	0	V <sub>CCB</sub>	V
		ŌE = HIGH	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC(A)</sub> = 0.8 V to 3.6 V	0	200	ns/V

### 10 Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	1	T <sub>amb</sub> = 25 °C			
			Min	Min Typ M			
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$					
		$I_{O}$ = -1.5 mA; $V_{CC(B)}$ = 0.8 V	-	0.69	-	V	
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$					
		I <sub>O</sub> = 1.5 mA; V <sub>CC(B)</sub> = 0.8 V	-	0.07	-	V	
II	input leakage current	A, $\overline{OE}$ input; V <sub>I</sub> = 0 V or 3.6 V; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 0.8 V to 3.6 V	-	±0.025	±0.25	μΑ	
I <sub>OFF</sub>	power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC(A)}$ or $V_{CC(B)} = 0$ V	-	±0.1	±1	μΑ	
R <sub>pd</sub>	pull-down resistance		-	50	-	kΩ	
Cı	input capacitance	A, $\overline{OE}$ input; $V_I = 0 \text{ V or } 3.3 \text{ V};$ $V_{CC(A)} = 3.3 \text{ V}$	-	1.2	-	pF	
Co	output capacitance	Yn; $V_O = 3.3 \text{ V or } 0 \text{ V}; V_{CC(B)} = 3.3 \text{ V}$	-	4.7	-	pF	

#### **Table 8. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T <sub>amb</sub> = -40 °	C to +85 °C	T <sub>amb</sub> = -40 °C	Unit	
			Min	Max	Min	Max	
$V_{IH}$	HIGH-level input voltage	H-level input A, OE input					
		V <sub>CC(A)</sub> = 0.8 V	0.70V <sub>CC(A)</sub>	-	0.70V <sub>CC(A)</sub>	-	V
		V <sub>CC(A)</sub> = 1.1 V to 1.95 V	0.65V <sub>CC(A)</sub>	-	0.65V <sub>CC(A)</sub>	-	V
		V <sub>CC(A)</sub> = 2.3 V to 2.7 V	1.6	-	1.6	-	V
		V <sub>CC(A)</sub> = 3.0 V to 3.6 V	2	-	2	-	V

Symbol	Parameter	Conditions	T <sub>amb</sub> = -40 °	C to +85 °C	T <sub>amb</sub> = -40 °	Unit	
			Min	Max	Min	Max	
V <sub>IL</sub>	LOW-level input	A, OE input					
	voltage	V <sub>CC(A)</sub> = 0.8 V	-	0.30V <sub>CC(A)</sub>	-	0.30V <sub>CC(A)</sub>	V
		V <sub>CC(A)</sub> = 1.1 V to 1.95 V	-	0.35V <sub>CC(A)</sub>	-	0.35V <sub>CC(A)</sub>	V
		V <sub>CC(A)</sub> = 2.3 V to 2.7 V	-	0.7	-	0.7	V
		V <sub>CC(A)</sub> = 3.0 V to 3.6 V	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$					
	output voltage	$I_O = -100 \mu A;$ $V_{CC(B)} = 0.8 \text{ V to } 3.6 \text{ V}$	V <sub>CC(B)</sub> - 0.1	-	V <sub>CC(B)</sub> - 0.1	-	V
		I <sub>O</sub> = -3 mA; V <sub>CC(B)</sub> = 1.1 V	0.85	-	0.85	-	V
		I <sub>O</sub> = -6 mA; V <sub>CC(B)</sub> = 1.4 V	1.05	-	1.05	-	V
		I <sub>O</sub> = -8 mA; V <sub>CC(B)</sub> = 1.65 V	1.2	-	1.2	-	V
		$I_O = -9 \text{ mA}; V_{CC(B)} = 2.3 \text{ V}$	1.75	-	1.75	-	V
		$I_O = -12 \text{ mA}; V_{CC(B)} = 3.0 \text{ V}$	2.3	-	2.3	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$					
	output voltage	$I_O = 100 \mu A;$ $V_{CC(B)} = 0.8 \text{ V to } 3.6 \text{ V}$	-	0.1	-	0.1	V
		I <sub>O</sub> = 3 mA; V <sub>CC(B)</sub> = 1.1 V	-	0.25	-	0.25	V
		I <sub>O</sub> = 6 mA; V <sub>CC(B)</sub> = 1.4 V	-	0.35	-	0.35	V
		I <sub>O</sub> = 8 mA; V <sub>CC(B)</sub> = 1.65 V	-	0.45	-	0.45	V
		I <sub>O</sub> = 9 mA; V <sub>CC(B)</sub> = 2.3 V	-	0.55	-	0.55	V
		I <sub>O</sub> = 12 mA; V <sub>CC(B)</sub> = 3.0 V	-	0.7	-	0.1 0.25 0.35 0.45	V
I <sub>I</sub>	input leakage current	A, $\overline{OE}$ input; V <sub>I</sub> = 0 V or 3.6 V; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 0.8 V to 3.6 V	-	±1	-	±5	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC(B)}$ = 0 V; $V_{CC(A)}$ = 0.8 V to 3.6 V	-	±5	-	±30	μΑ
I <sub>CC(A)</sub>	supply current A	$V_I = 0 \text{ V or } V_{CC(A)}; I_O = 0 \text{ A};$ $V_{CC(A)} = 0.8 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 0.8 \text{ V to } 3.6 \text{ V}$	-	8	-	50	μA
I <sub>CC(B)</sub>	supply current B	$V_I = 0 \text{ V or } V_{CC(A)}; I_O = 0 \text{ A};$ $V_{CC(A)} = 0.8 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 0.8 \text{ V to } 3.6 \text{ V}$	-	8	-	50	μΑ

### 11 Dynamic characteristics

Table 9. Typical dynamic characteristics at  $V_{CC(A)}$  = 0.8 V and  $T_{amb}$  = 25 °C <sup>[1]</sup>

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 6; for waveforms, see Figure 4 and Figure 5.

Symbol	Parameter	Conditions			Vc	C(B)			Unit
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
t <sub>pd</sub>	propagation delay	A to Yn	29	16	15	15	14	14	ns
t <sub>dis</sub>	disable time	OE to Yn	25	15	14	14	14	15	ns
t <sub>en</sub>	enable time	OE to Yn	33	18	16	16	15	15	ns

 $<sup>\</sup>begin{aligned} [1] & t_{pd} \text{ is the same as } t_{PLH} \text{ and } t_{PHL}; \\ & t_{dis} \text{ is the same as } t_{PLZ} \text{ and } t_{PHZ}; \\ & t_{en} \text{ is the same as } t_{PZL} \text{ and } t_{PZH}. \end{aligned}$ 

Table 10. Typical dynamic characteristics at  $V_{CC(B)}$  = 0.8 V and  $T_{amb}$  = 25 °C <sup>[1]</sup>

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 6; for waveforms, see Figure 4 and Figure 5.

Symbol	Parameter	Conditions		V <sub>CC(A)</sub>						
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V		
t <sub>pd</sub>	propagation delay	A to Yn	29	20	20	19	19	18	ns	
t <sub>dis</sub>	disable time	OE to Yn	25	17	16	16	15	15	ns	
t <sub>en</sub>	enable time	OE to Yn	33	24	23	23	22	22	ns	

 $<sup>\</sup>begin{aligned} [1] & t_{pd} \text{ is the same as } t_{PLH} \text{ and } t_{PHL}; \\ & t_{dis} \text{ is the same as } t_{PLZ} \text{ and } t_{PHZ}; \\ & t_{en} \text{ is the same as } t_{PZL} \text{ and } t_{PZH}. \end{aligned}$ 

Table 11. Dynamic characteristics for temperature range -40 °C to +85 °C  $^{[1]}$ 

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 6; for waveforms, see Figure 4 and Figure 5.

Symbol	Parameter	Conditions					V <sub>C</sub>	C(B)					Unit
			1.2 V:	±0.1 V	1.5 V:	±0.1 V	1.8 V±	0.15 V	2.5 V	±0.2 V	3.3 V:	±0.3 V	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V <sub>CC(A)</sub> =	1.1 V to 1.3 V						J						
t <sub>pd</sub>	propagation delay	A to Yn	0.9	14.7	0.8	11.2	0.7	9.9	0.6	8.8	0.6	8.5	ns
t <sub>dis</sub>	disable time	OE to Yn	1.0	14.7	0.9	12.2	0.9	12.1	8.0	10.8	1.0	11.7	ns
t <sub>en</sub>	enable time	OE to Yn	1.0	15.8	8.0	11.8	0.8	10.3	0.7	8.9	0.7	8.5	ns
V <sub>CC(A)</sub> =	1.4 V to 1.6 V	1	·	,		·			1	·	-	'	
t <sub>pd</sub>	propagation delay	A to Yn	0.8	13.2	0.7	9.5	0.6	8.2	0.5	6.7	0.5	6.2	ns
t <sub>dis</sub>	disable time	OE to Yn	0.9	12.4	8.0	9.7	0.8	9.7	0.7	8.3	0.9	9.0	ns
t <sub>en</sub>	enable time	OE to Yn	0.9	14.0	0.7	9.9	0.7	8.5	0.6	6.9	0.6	6.2	ns
V <sub>CC(A)</sub> =	1.65 V to 1.95	V								'		'	
t <sub>pd</sub>	propagation delay	A to Yn	0.8	12.5	0.7	8.9	0.6	7.6	0.5	6.1	0.5	5.4	ns
t <sub>dis</sub>	disable time	OE to Yn	0.9	11.7	8.0	9.0	0.8	8.8	0.7	7.4	0.8	8.2	ns
t <sub>en</sub>	enable time	OE to Yn	0.9	13.5	0.7	9.3	0.6	7.9	0.6	6.3	0.5	5.6	ns
V <sub>CC(A)</sub> = 2	2.3 V to 2.7 V	,	•			•			'	'		'	
t <sub>pd</sub>	propagation delay	A to Yn	0.8	12.0	0.6	8.3	0.6	6.9	0.5	5.4	0.4	4.7	ns
t <sub>dis</sub>	disable time	OE to Yn	0.9	11.0	0.7	8.3	0.8	8.0	0.6	6.5	0.8	7.2	ns
t <sub>en</sub>	enable time	OE to Yn	0.8	12.8	0.7	8.7	0.6	7.3	0.5	5.5	0.5	4.8	ns
V <sub>CC(A)</sub> = 3	3.0 V to 3.6 V				,			,					
t <sub>pd</sub>	propagation delay	A to Yn	8.0	11.6	0.6	8.0	0.5	6.5	0.5	5.1	0.4	4.4	ns
t <sub>dis</sub>	disable time	OE to Yn	0.9	10.8	0.7	8.0	0.7	7.7	0.6	6.2	0.7	6.9	ns
t <sub>en</sub>	enable time	OE to Yn	0.8	12.5	0.6	8.4	0.6	6.9	0.5	5.2	0.5	4.5	ns

 $<sup>\</sup>begin{aligned} \text{[1]} \quad & t_{\text{pd}} \text{ is the same as } t_{\text{PLH}} \text{ and } t_{\text{PHL}}; \\ & t_{\text{dis}} \text{ is the same as } t_{\text{PLZ}} \text{ and } t_{\text{PHZ}}; \\ & t_{\text{en}} \text{ is the same as } t_{\text{PZL}} \text{ and } t_{\text{PZH}}. \end{aligned}$ 

Table 12. Dynamic characteristics for temperature range -40 °C to +125 °C  $^{[1]}$ 

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 6; for waveforms, see Figure 4 and Figure 5.

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>								Unit		
			1.2 V:	±0.1 V	1.5 V:	±0.1 V	1.8 V±	0.15 V	2.5 V	±0.2 V	3.3 V:	±0.3 V	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V <sub>CC(A)</sub> = 1	1.1 V to 1.3 V												
t <sub>pd</sub>	propagation delay	A to Yn	0.9	15.7	0.8	12.1	0.7	10.8	0.6	9.7	0.6	9.3	ns
t <sub>dis</sub>	disable time	OE to Yn	1.0	16.5	0.9	13.8	0.9	13.7	0.8	12.3	1.0	13.1	ns
t <sub>en</sub>	enable time	OE to Yn	1.0	16.9	8.0	12.9	8.0	11.4	0.7	9.7	0.7	9.2	ns
$V_{CC(A)} = 1$	1.4 V to 1.6 V		•	1		•				'		'	,
t <sub>pd</sub>	propagation delay	A to Yn	0.8	14.1	0.7	10.4	0.6	9.0	0.5	7.3	0.5	6.8	ns
t <sub>dis</sub>	disable time	OE to Yn	0.9	14.0	0.8	11.0	0.8	11.0	0.7	9.5	0.9	10.2	ns
t <sub>en</sub>	enable time	OE to Yn	0.9	15.1	0.7	10.9	0.7	9.3	0.6	7.6	0.6	6.8	ns
$V_{CC(A)} = 1$	1.65 V to 1.95	V											
t <sub>pd</sub>	propagation delay	A to Yn	8.0	13.6	0.7	9.7	0.6	8.3	0.5	6.7	0.5	6.0	ns
t <sub>dis</sub>	disable time	OE to Yn	0.9	13.4	8.0	10.2	8.0	10.0	0.7	8.4	0.8	9.2	ns
t <sub>en</sub>	enable time	OE to Yn	0.9	14.5	0.7	10.2	0.6	8.7	0.6	6.9	0.5	6.2	ns
$V_{CC(A)} = 2$	2.3 V to 2.7 V				,								,
t <sub>pd</sub>	propagation delay	A to Yn	8.0	12.9	0.6	9.1	0.6	7.6	0.5	5.9	0.4	5.2	ns
t <sub>dis</sub>	disable time	OE to Yn	0.9	12.5	0.7	9.4	0.8	9.1	0.6	7.5	0.8	8.2	ns
t <sub>en</sub>	enable time	OE to Yn	0.8	13.7	0.7	9.5	0.6	8.0	0.5	6.1	0.5	5.3	ns
$V_{CC(A)} = 3$	3.0 V to 3.6 V												
t <sub>pd</sub>	propagation delay	A to Yn	8.0	12.5	0.6	8.7	0.5	7.2	0.5	5.6	0.4	4.9	ns
t <sub>dis</sub>	disable time	OE to Yn	0.9	12.1	0.7	9.1	0.7	8.8	0.6	7.1	0.7	7.7	ns
t <sub>en</sub>	enable time	OE to Yn	0.8	13.4	0.6	9.2	0.6	7.6	0.5	5.7	0.5	4.9	ns

 $<sup>\</sup>begin{aligned} \text{[1]} \quad & t_{\text{pd}} \text{ is the same as } t_{\text{PLH}} \text{ and } t_{\text{PHL}}; \\ & t_{\text{dis}} \text{ is the same as } t_{\text{PLZ}} \text{ and } t_{\text{PHZ}}; \\ & t_{\text{en}} \text{ is the same as } t_{\text{PZL}} \text{ and } t_{\text{PZH}}. \end{aligned}$ 

Table 13. Dynamic characteristics for temperature range -40 °C to +85 °C and -40 °C to +125 °C

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 6.

Symbol	Parameter	Conditions	$V_{CC(A)} = V_{CC(B)}$						
			1.2 V±0.1 V	1.5 V±0.1 V	1.8 V±0.15 V	2.5 V±0.2 V	3.3 V±0.3 V		
			Max	Max	Max	Max	Max		
T <sub>amb</sub> = -40 °C to +85 °C									
t <sub>sk(o)</sub>	output skew time	between any output	0.7	0.4	0.3	0.2	0.2	ns	
T <sub>amb</sub> = -40 °C to +125 °C									
t <sub>sk(o)</sub>	output skew time	between any output	0.9	0.5	0.4	0.3	0.2	ns	

### Table 14. Typical power dissipation capacitance at $T_{amb}$ = 25 °C <sup>[1] [2]</sup>

Symbol Parameter		Conditions	$V_{CC(A)} = V_{CC(B)}$						
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
'	power dissipation	Yn; outputs enabled	36	36	37	37	41	46	pF
	capacitance	Yn; outputs disabled	2.9	3.2	3.4	3.5	3.7	3.9	pF

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

fo = output frequency in MHz;

C<sub>L</sub> = load capacitance in pF;

 $V_{CC}$  = supply voltage in V;  $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

[2]  $f_i = 10 \text{ MHz}$ ;

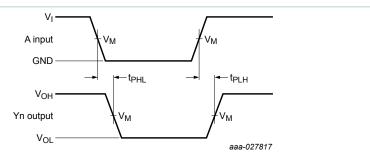
 $V_I = GND \text{ to } V_{CC(A)};$ 

 $t_r = t_f = 1 \text{ ns};$ 

 $C_L = 0 pF;$ 

 $R_L = \infty \Omega$ .

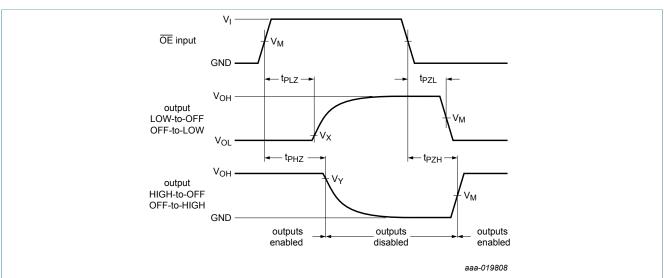
#### 11.1 Waveforms and test circuit



Measurement points are given in <u>Table 15</u>.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage levels that occur with the output load.

Figure 4. The data input (A) to output (Yn) propagation delay times



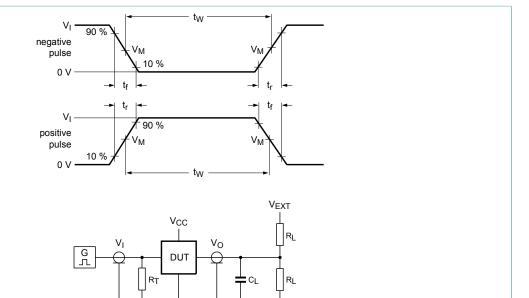
Measurement points are given in Table 15.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage levels that occur with the output load.

Figure 5. Enable and disable times

Table 15. Measurement points

Supply voltage	Input	Output				
V <sub>CC(A)</sub> , V <sub>CC(B)</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>		
0.8 V to 1.6 V	0.5V <sub>CC(A)</sub>	0.5V <sub>CC(B)</sub>	V <sub>OL</sub> + 0.1 V	V <sub>OH</sub> - 0.1 V		
1.65 V to 2.7 V	0.5V <sub>CC(A)</sub>	0.5V <sub>CC(B)</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V		
3.0 V to 3.6 V	0.5V <sub>CC(A)</sub>	0.5V <sub>CC(B)</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V		



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Test data is given in Table 16

R<sub>L</sub> = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance.

 $V_{EXT}$  = External voltage for measuring switching times.

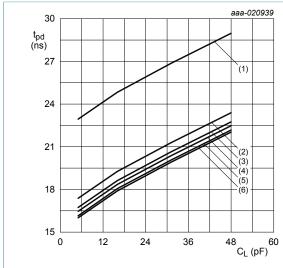
Figure 6. Test circuit for measuring switching times

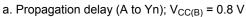
Table 16. Test data

Supply voltage	Input		Load		V <sub>EXT</sub>		
$V_{CC(A)}, V_{CC(B)}$	VI	Δt/ΔV <sup>[1]</sup>	CL	R <sub>L</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 1.6 V	$V_{CC(A)}$	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	2V <sub>CC(B)</sub>
1.65 V to 2.7 V	$V_{CC(A)}$	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	2V <sub>CC(B)</sub>
3.0 V to 3.6 V	$V_{CC(A)}$	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	2V <sub>CC(B)</sub>

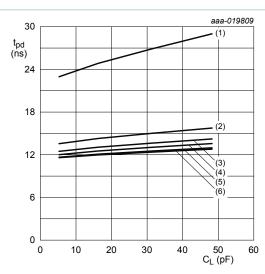
[1] dV/dt ≥ 1.0 V/ns

### 11.2 Typical propagation delay characteristics





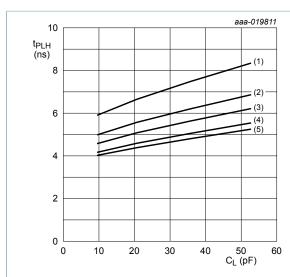
- (1)  $V_{CC(A)} = 0.8 \text{ V}$
- (2)  $V_{CC(A)} = 1.2 \text{ V}$
- (3)  $V_{CC(A)} = 1.5 \text{ V}$
- (4)  $V_{CC(A)} = 1.8 \text{ V}$
- (5)  $V_{CC(A)} = 2.5 \text{ V}$
- (6)  $V_{CC(A)} = 3.3 \text{ V}$

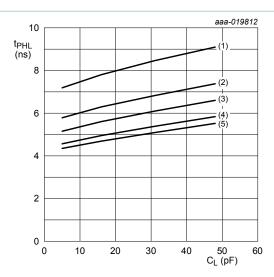


b. Propagation delay (A to Yn); V<sub>CC(A)</sub> = 0.8 V

- (1)  $V_{CC(B)} = 0.8 \text{ V}$
- (2)  $V_{CC(B)} = 1.2 \text{ V}$
- (3)  $V_{CC(B)} = 1.5 \text{ V}$
- (4)  $V_{CC(B)} = 1.8 \text{ V}$
- (5)  $V_{CC(B)} = 2.5 \text{ V}$
- (6)  $V_{CC(B)} = 3.3 \text{ V}$

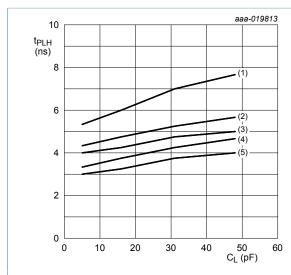
Figure 7. Typical propagation delay versus load capacitance; T<sub>amb</sub> = 25 °C





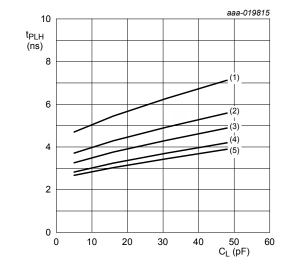
- a. LOW to HIGH propagation delay (A to Yn);  $V_{CC(A)} = 1.2 \text{ V}$  b. HIGH to LOW propagation delay (A to Yn);  $V_{CC(A)} = 1.2 \text{ V}$ 
  - (1)  $V_{CC(B)} = 1.2 \text{ V}$
  - (2)  $V_{CC(B)} = 1.5 \text{ V}$
  - (3)  $V_{CC(B)} = 1.8 \text{ V}$
  - (4)  $V_{CC(B)} = 2.5 \text{ V}$
  - (5)  $V_{CC(B)} = 3.3 \text{ V}$

Figure 8. Typical propagation delay versus load capacitance; T<sub>amb</sub> = 25 °C



a. LOW to HIGH propagation delay (A to Yn);

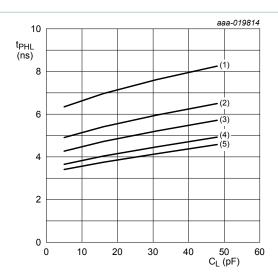
$$V_{CC(A)} = 1.5 \text{ V}$$



c. LOW to HIGH propagation delay (A to Yn);

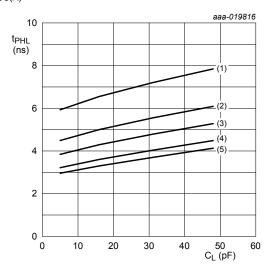
$$V_{CC(A)} = 1.8 \text{ V}$$

- (1)  $V_{CC(B)} = 1.2 \text{ V}$
- (2)  $V_{CC(B)} = 1.5 \text{ V}$
- (3)  $V_{CC(B)} = 1.8 \text{ V}$
- (4)  $V_{CC(B)} = 2.5 \text{ V}$
- (5)  $V_{CC(B)} = 3.3 \text{ V}$



b. HIGH to LOW propagation delay (A to Yn);

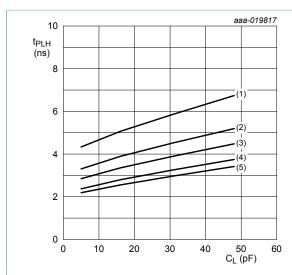
$$V_{CC(A)} = 1.5 \text{ V}$$



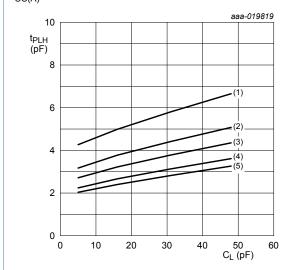
d. HIGH to LOW propagation delay (A to Yn);

$$V_{CC(A)} = 1.8 \text{ V}$$

Figure 9. Typical propagation delay versus load capacitance;  $T_{amb}$  = 25  $^{\circ}$ C



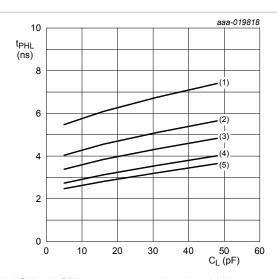
a. LOW to HIGH propagation delay (A to Yn);  $V_{CC(A)} = 2.5 \text{ V}$ 



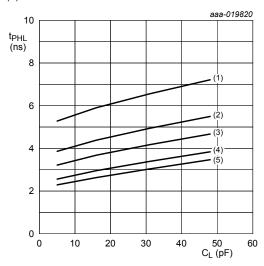
c. LOW to HIGH propagation delay (A to Yn);

$$V_{CC(A)} = 3.3 \text{ V}$$

- (1)  $V_{CC(B)} = 1.2 \text{ V}$
- (2)  $V_{CC(B)} = 1.5 \text{ V}$
- (3)  $V_{CC(B)} = 1.8 \text{ V}$
- (4)  $V_{CC(B)} = 2.5 \text{ V}$
- $(5) V_{CC(B)} = 3.3 V$



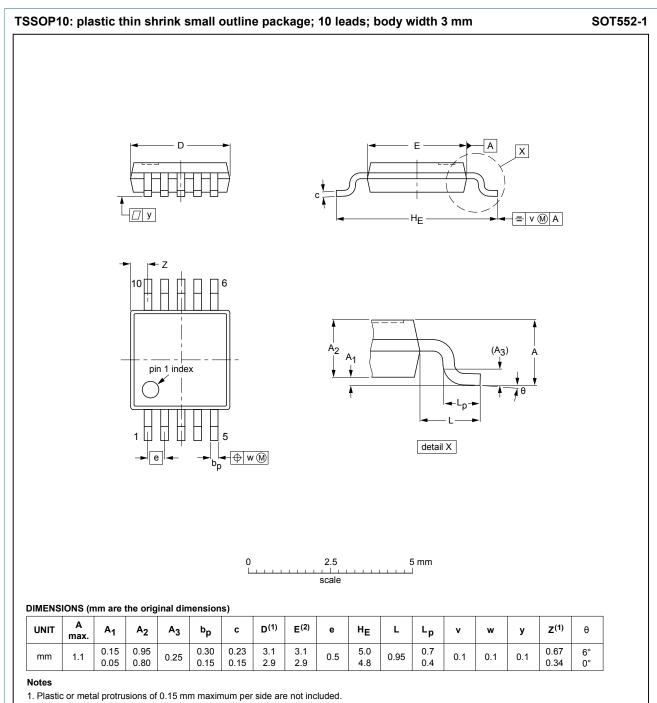
b. HIGH to LOW propagation delay (A to Yn);  $V_{CC(A)} = 2.5 \text{ V}$ 



d. HIGH to LOW propagation delay (A to Yn);  $V_{CC(A)}$  = 3.3 V

Figure 10. Typical propagation delay versus load capacitance; T<sub>amb</sub> = 25 °C

### 12 Package outline



2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

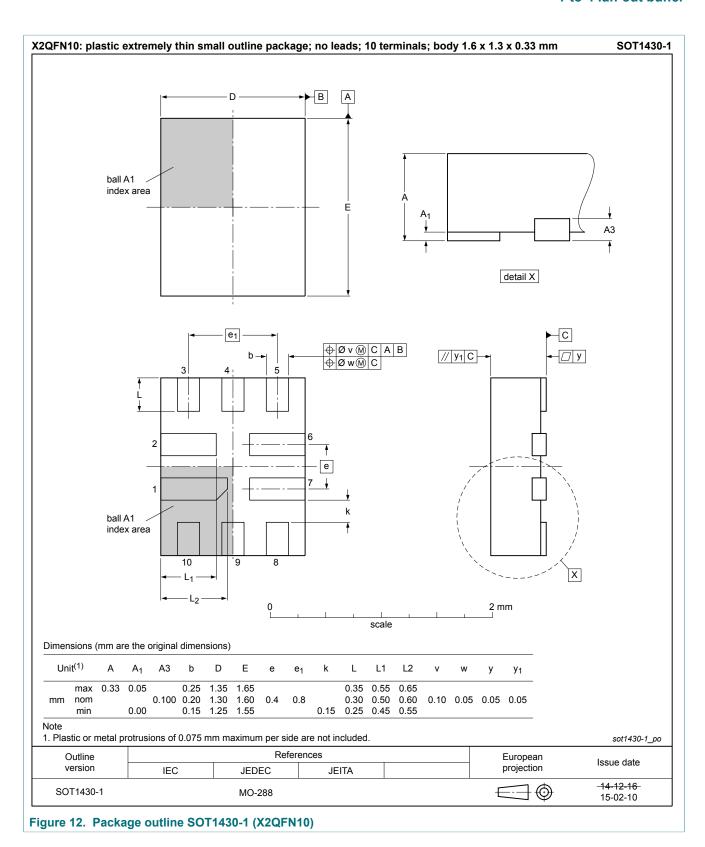
OUTLINE		REFER	EUROPEAN	ICCUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT552-1						<del>-99-07-29</del> 03-02-18	

Figure 11. Package outline SOT552-1 (TSSOP10)

74AVC1T1004

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### 13 Abbreviations

#### **Table 17. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model

### 14 Revision history

#### Table 18. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AVC1T1004 v.1	20180423	Product data sheet	-	-

### 15 Legal information

#### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## 74AVC1T1004

1-to-4 fan-out buffer

### **Contents**

1	General description	1
2	Features and benefits	
3	Ordering information	2
4	Marking	
5	Functional diagram	
6	Pinning information	
6.1	Pinning	
6.2	Pin description	
7	Functional description	
8	Limiting values	
9	Recommended operating conditions	
10	Static characteristics	
11	Dynamic characteristics	7
11.1	Waveforms and test circuit	
11.2	Typical propagation delay characteristics	13
12	Package outline	
13	Abbreviations	
14	Revision history	19
15	Legal information	

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